

Description

The NCE0130 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

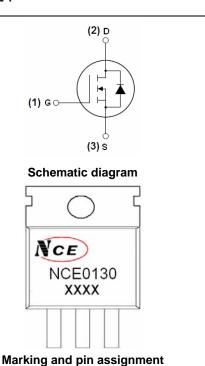
- V_{DS} = 100V, I_{D} =30A $R_{DS(ON)}$ < 28mΩ @ V_{GS} =10V (Typ:24 mΩ)
- Special process technology for high ESD capability
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



TO-220-3L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0130	NCE0130	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Symbol	Parameter	Limit	Unit
V _{DS}	Drain-Source Voltage	100	V
V _G s	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous	30	А
I _D (100℃)	Drain Current-Continuous(TC=100°C)	21	А
I _{DM}	Pulsed Drain Current	70	А
P_{D}	Maximum Power Dissipation	75	W
	Derating factor	0.5	W/℃
E _{AS}	Single pulse avalanche energy (Note 5)	256	mJ
T_{J}, T_{STG}	Operating Junction and Storage Temperature Range	-55 To 175	°C



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NCE0130

Thermal Characteristic

R _{eJC}	Thermal Resistance, Junction-to-Case (Note 2)	2.0	°C/W
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Syı	mbol	Parameter	Condition	Min	Тур	Max	Unit
Off Characteristics							
BV _{DSS}	Drain-Source Break	down Voltage	tage V _{GS} =0V I _D =250μA		110	-	V
I _{DSS}	Zero Gate Voltage	Drain Current	V _{DS} =100V,V _{GS} =0V	-	-	1	μΑ
I _{GSS}	Gate-Body Leak	age Current	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics	(Note 3)						
V _{GS(th)}	Gate Threshol	d Voltage	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	3	4	V
R _{DS(ON)}	Drain-Source On-St	ate Resistance	V _{GS} =10V, I _D =15A	-	24	28	mΩ
g FS	Forward Transco	onductance	V _{DS} =5V,I _D =10A	-	15	-	S
Dynamic Character	istics (Note4)				•		
C _{Iss}	Input Capac	citance	\\ 05\\\\ 01	-	2000	-	PF
Coss	Output Capa	ıcitance	V _{DS} =25V,V _{GS} =0V,	-	300	-	PF
C _{rss}	Reverse Transfer	Capacitance	F=1.0MHz	-	250	-	PF
Switching Characte	ristics (Note 4)			•	JI.		
t _{d(on)}	Turn-on Dela	ay Time		-	7	-	nS
tr	Turn-on Ris	e Time	V_{DD} =50V, R_L =5 Ω	-	7	-	nS
$t_{d(off)}$	Turn-Off Dela	ay Time	V_{GS} =10V, R_{GEN} =3 Ω	-	29	-	nS
t _f	Turn-Off Fa	II Time		-	7	-	nS
Qg	Total Gate (Charge)/ 50\/ L 40A	-	39	-	nC
Q _{gs}	Gate-Source	Charge	V_{DS} =50V, I_{D} =18A, V_{GS} =10V	-	8	-	nC
Q _{gd}	Gate-Drain	Charge	V _{GS} =10V	-	12	-	nC
Drain-Source Diode	Characteristics						
V _{SD}	Diode Forward V	oltage (Note 3)	V _{GS} =0V,I _S =20A	-	-	1.2	V
Is	Diode Forward C		-	-	-	30	Α
t _{rr}	Reverse Recov	ery Time	TJ = 25°C, IF = 18A	-	32	-	nS
Qrr	Reverse Recove	ery Charge	di/dt = 100A/µs ^(Note3)	-	53	-	nC
ton	Forward Turn-	On Time	Intrinsic turn-on time is negligible (turn-on is dominated by LS+				v I S+I D)

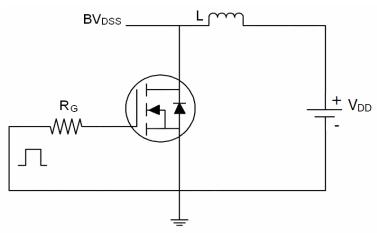
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t \leq 10 sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS Condition : Tj=25 $^{\circ}$ C,V_{DD}=50V,V_G=10V,L=0.5mH,Rg=25 Ω , I_{AS}=32A

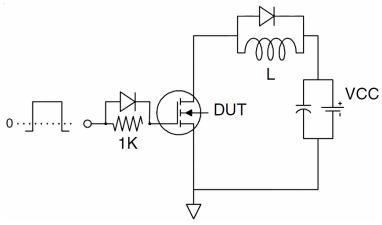


Test Circuit

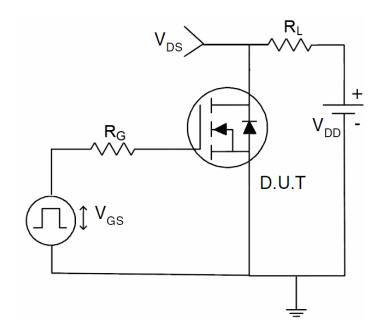
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

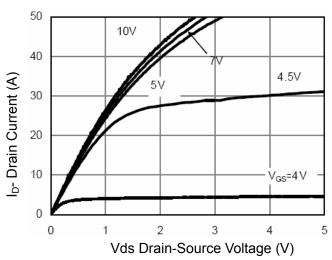


Figure 1 Output Characteristics

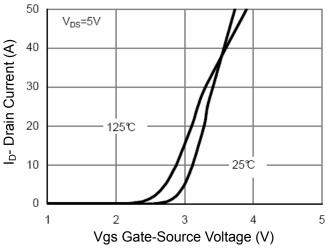


Figure 2 Transfer Characteristics

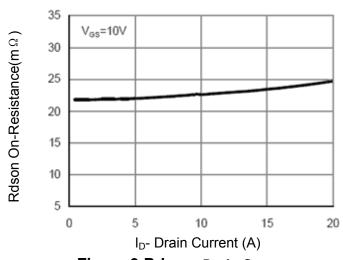


Figure 3 Rdson- Drain Current

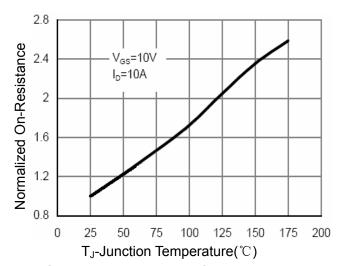


Figure 4 Rdson-JunctionTemperature

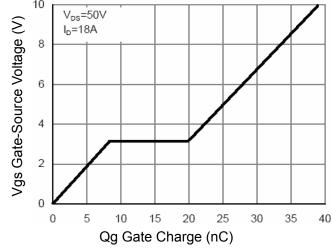


Figure 5 Gate Charge

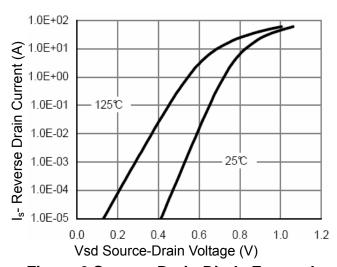
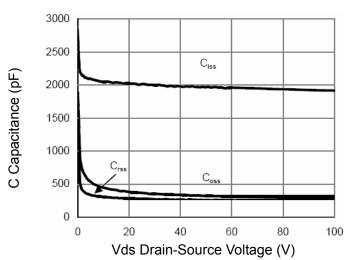


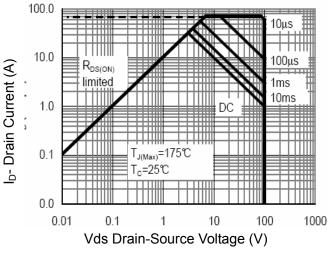
Figure 6 Source- Drain Diode Forward



120 100 Power Dissipation (W) 80 60 40 20 0 0 25 75 100 125 150 175 T_J -Junction Temperature ($^{\circ}$ C)

Figure 7 Capacitance vs Vds





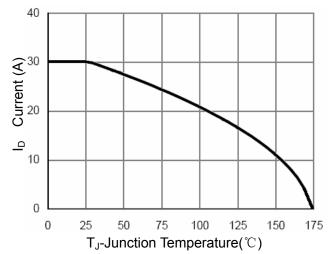


Figure 8 Safe Operation Area

Figure 10ID Current- Junction Temperature

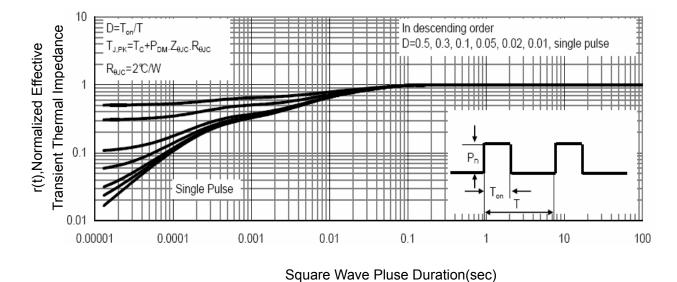
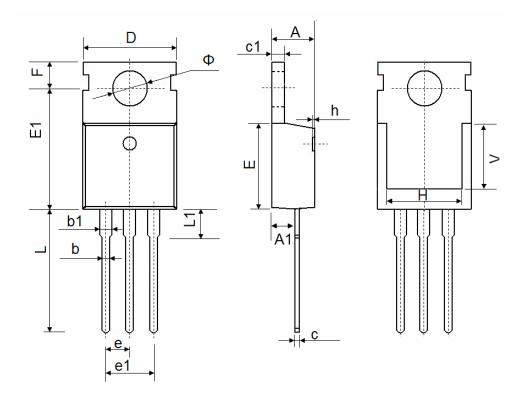


Figure 11 Normalized Maximum Transient Thermal Impedance



TO-220-3L Package Information



Occupation of	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
Е	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.54	0 TYP.	TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.50	0 REF.	0.295 REF.		
Ф	3.400	3.800	0.134	0.150	



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